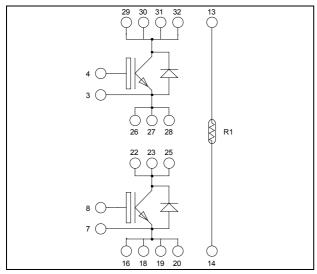


Phase leg NPT IGBT Power Module Power Module





Pins 29/30/31/32 must be shorted together
Pins 26/27/28/22/23/25 must be shorted together
to achieve a phase leg
Pins 16/18/19/20 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Kelvin emitter for easy drive
- Internal thermistor for temperature monitoring
- High level of integration
- AlN substrate for improved thermal performance

Benefits

- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	130	
I_{C}	Continuous Conector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	100	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Maximum Power Dissipation	$T_C = 25^{\circ}C$	780	W
RBSOA	Reverse Bias Safe Operating Area	$T_{\rm J} = 150^{\circ}{\rm C}$	200A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
		$I_{\rm C} = 100 A$	$T_j = 125$ °C		3.9		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 4mA$		4.5	5.5	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			6.5		
Coes	Output Capacitance				1		nF
Cres	Reverse Transfer Capacitance				0.5		
Q_{G}	Gate charge	$V_{GE} = \pm 15V ; V_{CE} = 600V$ $I_{C} = 100A$			1.1		μС
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (25°C)				
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 100 \text{A}$	$V_{Bus} = 600V$		310		ns
T_{f}	Fall Time	$R_G = 5.6\Omega$			20		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)			130		
T _r	Rise Time	$V_{GE} = \pm 15V$			60		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 100A$			360		
T_{f}	Fall Time	$R_G = 5.6\Omega$	_		30		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		12		Т
E_{off}	Turn-off Switching Energy	$I_C = 100A$ $R_G = 5.6\Omega$	$T_j = 125$ °C		5		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; V_{Bi} $t_p \le 10 \mu s$; $T_j =$			650		A

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
T	Maximum Reverse Leakage Current	$V_R = 1200V$ $T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$	$V_{p}=1200V$		150	Δ	
I_{RM}	Waximum Reverse Leakage Current					600	μA
I_F	DC Forward Current		Tc = 100°C		60		A
		$I_F = 60A$			2.6	3.1	
$V_{\rm F}$	Diode Forward Voltage	$I_F = 120A$			3.2		V
		$I_F = 60A$	$T_j = 125$ °C		1.8		
t	Reverse Recovery Time		$T_j = 25$ °C		300		ns
t_{rr}	Reverse Recovery Time	$I_F = 60A$ $V_R = 800V$	$T_{\rm j} = 125^{\circ}{\rm C}$		380		115
Q _{rr}	Payarsa Pacayary Charga	$di/dt = 400 \text{A/}\mu\text{s}$		720		nC	
	Reverse Recovery Charge	·	$T_{j} = 125^{\circ}C$		3400		пС



Thermal and package characteristics

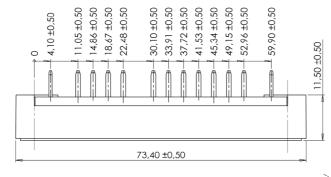
Symbol	Characteristic			Min	Тур	Max	Unit
D	Junction to Case Thermal Resistance		IGBT			0.16	°C/W
R_{thJC}			Diode			0.50	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2	·	3	N.m
Wt	Package Weight					110	g

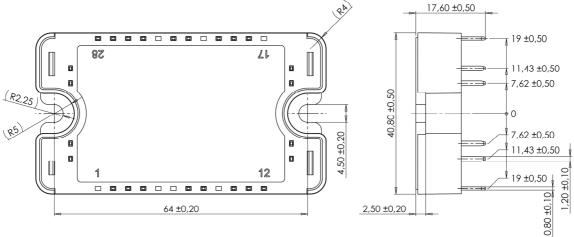
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symb	l Characteristic			Min	Тур	Max	Unit
R_{25}	Resistance @ 25°C				50		kΩ
ΔR_{25}	25				5		%
$B_{25/8}$	$T_{25} = 298.15 \text{ K}$				3952		K
$\Delta B/1$			T _C =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \\ R_{T}: \text{ Thermistor value at T}$$

SP3 Package outline (dimensions in mm)

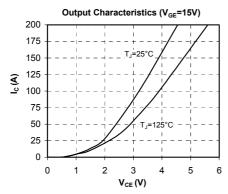


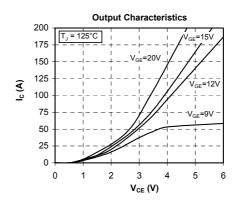


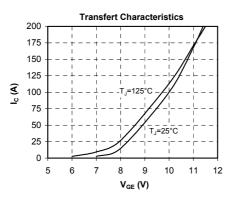
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

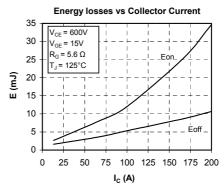


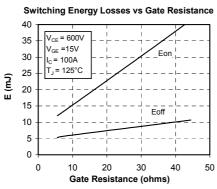
Typical Performance Curve

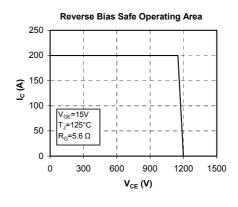


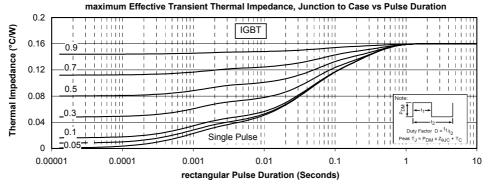




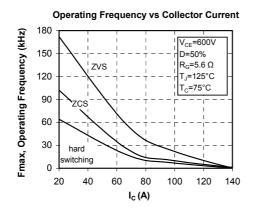


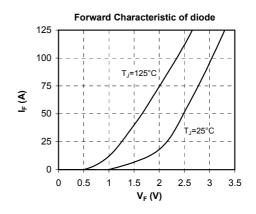


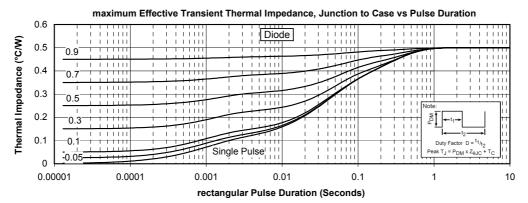












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